

	L #	Hits	Search Text	DBs
1	L1	4009	solid adj state adj relay\$1	USPAT; US - PGP UB; EPO; JPO; DERWENT; IBM _ TD B
2	L3	9102	solid adj state adj switch\$3	USPAT; US - PGP UB; EPO; JPO; DERWENT; IBM _ TD B
3	L4	12824	1 or 3	USPAT; US - PGP UB; EPO; JPO; DERWENT; IBM _ TD B
4	L5	60	photovoltaic near diode near array\$1	USPAT; US - PGP UB; EPO; JPO; DERWENT; IBM _ TD B
5	L6	20703	photovoltaic	USPAT; US - PGP UB; EPO; JPO; DERWENT; IBM _ TD B

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6	L7	241	4 and 6	USPAT; US - PGP UB; EPO; JPO; DERWENT; IBM_TD B
7	L8	117128	bi\$1direction\$2	USPAT; US - PGP UB; EPO; JPO; DERWENT; IBM_TD B
8	L9	299	8 same 4	USPAT; US - PGP UB; EPO; JPO; DERWENT; IBM_TD B
9	L10	9	6 and 9	USPAT; US - PGP UB; EPO; JPO; DERWENT; IBM_TD B
10	L11	391	bi\$1polar same 4	USPAT; US - PGP UB; EPO; JPO; DERWENT; IBM_TD B

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11	L12	11	6 and 11	USPAT; US - PGP UB; EPO; JPO; DERWENT; IBM_TD_B
12	L13	63456	(bi\$1polar near transistor\$1) or (bi\$1direction\$2 near switch\$3)	USPAT; US - PGP UB; EPO; JPO; DERWENT; IBM_TD_B
13	L14	893	13 and 4	USPAT; US - PGP UB; EPO; JPO; DERWENT; IBM_TD_B
14	L15	37	6 and 14	USPAT; US - PGP UB; EPO; JPO; DERWENT; IBM_TD_B